

US-Request

Page 1 of 2

APPLICATION DATA SHEET

Electronic Version v14

Stylesheet Version v14.0

Title of Invention	[MULTI-LEVEL MEMORY CELL AND FABRICATING METHOD THEREOF]		
Application Type: regular, utility Attorney Docket Number: 11039-US-PA			
Correspondence address: Customer Number: 31561 *31561*			
Priority Data: Doc.No: 92113048; Country - TW; Date: 2003-05-14 us-priority-not-claimed			
Inventors Information: <u>Inventor 1:</u> Applicant Authority Type: Inventor Citizenship: TW Name prefix: Mr. Given Name: Chiu-Tsung Family Name: Huang City of Residence: Hsinchu Country of Residence: TW Address-1 of Mailing Address: No. 37, Alley 1, Lane 30, Fu-Chiun St., Address-2 of Mailing Address: City of Mailing Address: Hsinchu State of Mailing Address: Postal Code of Mailing Address: Country of Mailing Address: TW Phone: Fax: E-mail: <u>Inventor 2:</u> Applicant Authority Type: Inventor Citizenship: TW Name prefix: Mr.			

file:///C:/Program%20Files/USPTO/ePAVE/efiling/11039/11039-usrequ.xml

7/25/2003

US-Request

Page 2 of 2

Given Name: Ko-Hsing
Family Name: Chang
City of Residence: Hsinchu
Country of Residence: TW
Address-1 of Mailing Address: 12F-1, No. 88, Ta-Hsueh Rd.,
Address-2 of Mailing Address:
City of Mailing Address: Hsinchu
State of Mailing Address:
Postal Code of Mailing Address:
Country of Mailing Address: TW
Phone:
Fax:
E-mail:

Attorney Information:

practitioner(s) at Customer Number:

31561 *31561*

as our attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.